

United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/768,944	01/30/2004	Muhammad Asif Khan	SETI-0001DIV	8944
23550 7590 05/05/2006			EXAMINER	
HOFFMAN WARNICK & D'ALESSANDRO, LLC			ERDEM, FAZLI	
75 STATE STREET		ART UNIT	PAPER NUMBER	
14TH FL ALBANY, N	Y 12207		2826	
1122.11.1,			DATE MAILED: 05/05/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

:						
2	Application No.	Applicant(s)				
	10/768,944	KHAN ET AL.				
Office Action Summary	Examiner	Art Unit				
	Fazli Erdem	2826				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 16(a). In no event, however, may a reply be tirgoing 17 iiii apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	N. nely filed I the mailing date of this communication. ID (35 U.S.C. § 133).				
Status						
1)⊠ Responsive to communication(s) filed on <u>17 February 2006</u> .						
	·					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the ments is						
closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims						
4) Claim(s) <u>20-32</u> is/are pending in the application.						
4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.						
6) Claim(s) 20,21,24,25 and 28-32 is/are rejected.						
7) Claim(s) 22,23,26 and 27 is/are objected to.						
8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
9)☐ The specification is objected to by the Examiner.						
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).						
11)☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.						
Priority under 35 U.S.C. § 119						
12)☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a)☐ All b)☐ Some * c)☐ None of:						
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority documents have been received in Application No						
3. Copies of the certified copies of the priority documents have been received in this National Stage						
application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
See the attached detailed Office action for a list of the certified copies not received.						
		•				
Attachment(s)						
1) Motice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summar Paper No(s)/Mail D	Date				
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 1/30/2004.	5) Notice of Informal 6) Other:	Patent Application (PTO-152)				

Art Unit: 2826

DETAILED ACTION

Allowable Subject Matter

- 1. Claims 22, 23, 26 and 27 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 2. The following is a statement of reasons for the indication of allowable subject matter:

 Prior art failed to establish semiconductor device with the required molar percentage of Al and

 In.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 20, 21, 31 and 32 rejected under 35 U.S.C. 103(a) as being unpatentable over Edmond et al. (5,523,589) in view of Sugawara et al. (6,359,292)

Regarding Claims 20, 21,31 and 32, Edmond et al. disclose a vertical geometry light emitting diode with group III nitrid active layer and extended lifetime where in Fig. 1, it is disclosed a SiC (silicon carbide) substrate 21, a buffer which is nitride based and can include In (Indium) 23 on substrate, and another nitride based layer 27 which can include a quaternary layer. Edmond et al. fail to disclose the required substrate and the required quaternary layer. However, Sugawara et al. disclose a semiconductor light emitting element where in Fig. 1 and in

Art Unit: 2826

paragraphs 5-8, active layer 105 is disclosed to be quaternary AlInGaN and is located over buffer layer 102.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required substrate and the required quaternary layer in Edmond et al. as taught by Sugawara et al. in order to have a semiconductor device with increased performance.

5. Claims 24, 25, 28, 29 and 30 rejected under 35 U.S.C. 103(a) as being unpatentable over Edmond et al. (5,523,589) in view of Sugawara et al. (6,359,292) further in view of Sasanuma et al. (JP411243251)

Regarding Claims 24,25, 28, 29 and 30, Edmond et al. disclose a vertical geometry light emitting diode with group III nitride active layer and extended lifetime where in Fig. 1, it is disclosed a SiC (silicon carbide) substrate 21, a buffer which is nitride based and can include In (Indium) 23 on substrate, and another nitride based layer 27 which can include a quaternary layer. Edmond et al. fail to disclose the required substrate, the required quaternary layer and the required multilevel quaternary layer. However, Sugawara et al. disclose a semiconductor light emitting element where in Fig. 1 and in paragraphs 5-8, active layer 105 is disclosed to be quaternary AlInGaN and is located over buffer layer 102. Furthermore, Sasanuma et al. disclose a semiconductor laser where in Fig. 6, the required InGaN/InGaAlN, multilayer quaternary structure is disclosed.

Art Unit: 2826

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required substrate and the required quaternary layer and the required multilayer quaternary structure in Edmond et al. as taught by Sugawara et al. and Sasanuma et al. respectively, in order to have a semiconductor device with increased performance.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

FE April 27, 2006

Art Unit: 2826

NATHAN J. FRANCH SUPERVISORY PATENT EXCLANGED TECHNOLOGY CLEATER TO TO